

30V 2.4A Synchronous Buck Converter

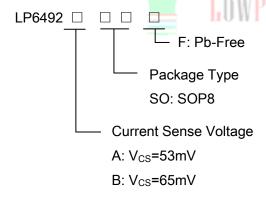
General Description

The LP6492 is a synchronous, rectified, step-down, switch-mode converter with built-in power MOSFET. The LP6492 offers a very compact solution that achieves a maximum of 2.4A of continuous output current.

The LP6492 has synchronous mode operation for high efficiency over the output current load range. Current-mode operation provides fast transient response and eases loop stabilization.

The LP6492 requires a minimum number of readily available standard external components. Other features include cable compensation, programmable current limit and thermal shutdown.

Order Information



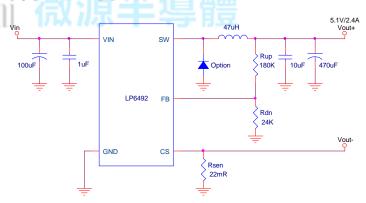
Applications

- ♦ Car Charger
- ♦ Pre-Regulator for Linear Regulators
- ♦ Distributed Power Systems

Features

- Wide 8V to 30V Continuous Operating Input Range
- 78mΩ/65mΩ Low R_{DS(ON)} Internal Power MOSFET
- Up to 93% Efficiency
- Default 160kHz Switching Frequency
- Internal Soft Start
- Output Line Drop Compensation
- Over-Current Protection (OCP) programmable with External Resistor
- ◆ No Loop Compensation Required
- ◆ Thermal Shutdown
- Available in SOP8 Package

Typical Application Circuit



Marking Information

Device	Marking	Package	Shipping
LP6492A	LPS		
	LP6492	SOP8	2.5K/REEL
LP6492B	xxx		

Marking indication:

Y:Production year W:Production week X:Production batch

LP6492-02 Jun

Jun.-2017

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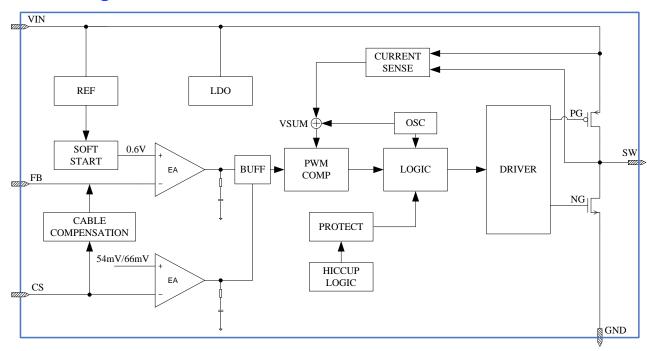
Functional Pin Description

Package Type	Pin Configurations			
SOP8	FB 1	8 GND 7 GND 6 SW 5 SW		

Pin Description

Pin	Name	Description		
1	FB	Voltage Feedback. The feedback voltage is 0.6V.		
2	CS	Output Current Sense PIN.		
3	GND	Ground.		
4	VIN	Input Supply Voltage.		
5,6	SW	Switch PIN.		
7,8	GND	Power Ground.		
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Function Diagram



LP6492-02 Jun.-2017 Email: marketing@lowpowersemi.com www.lowpowersemi.com Page 2 of 6

Preliminary Datasheet

LP6492

Absolute N	Maximum	Ratings	Note 1
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\diamond	VIN to GND0.3V to +36V
	SW to GND0.3V to +36V
	All other pin to GND
	Storage temperature range
	Maximum Operating Junction temperature+150°C
	Maximum Soldering Temperature (at leads, 10 sec) +260°C

Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Information

- ♦ Thermal Resistance (θ_{JA}) ------ 80°C/W

ESD Susceptibility

- ♦ HBM(Human Body Mode) ------ 2KV
- ♦ MM(Machine Mode) ----- 200V

Recommended Operating Conditions

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Electrical Characteristics

V_{IN}=12V , T_A=25°C, unless otherwise noted

Parameter	Symbol	Condition	Min	Тур	Max	Units
0 1 - 0 1	ΙQ	No switching, V _{FB} =0.8V		0.73	1	mA
Supply Current	Isw	Switching, I _{load} =0A		10	20	mA
VIN Under Voltage Lockout Threshold Rising	V _{IN_UVLO}	V _{IN} rising	6.6	7.3	8	V
VIN Under Voltage Lockout Threshold Hysteresis	V _{IN_HYS}			1		V
Oscillator Frequency	Fsw	V _{FB} =0.6V		160		KHz
Maximum Duty Cycle	Dмаx				98	%
FB Voltage Reference	V _{REF}		0.588	0.6	0.612	V
OVP Voltage Reference	V _{REF-OVP}			0.706		V
SCP voltage Reference	V _{REF_SCP}			0.395		V
CS Voltage Reference	.,	LP6492A	48	53	58	mV
	Vcs	LP6492B	58	65	72	mV
Line Compensation Current	I _{FB}	erSemi 微源=	上連	1.5		uA
SCP Frequency	Fsw ₁			61		KHz
Current Limit	ILIMIT			4		Α
High-Side Switch on Resistance	R _{DSON-H}			78		mΩ
Low-Side Switch on Resistance	R _{DSON-L}			65		mΩ
Thermal Shutdown	Тотр	Temp rising		150		°C
Thermal Shutdown Hysteresis	T _{OTP_HYS}			15		°C
Hiccup Time	thiccup			260		ms
Soft-start Time	tss			2.7		ms

LP6492-02 Jun.-2017 Email: marketing@lowpowersemi.com www.lowpowersemi.com Page 4 of 6

LP6492

Application Information

The LP6492 operates by a constant frequency, current mode architecture. The output voltage is set by an external divider returned to the FB pin. An error amplifier compares the divided output voltage with a reference voltage of 0.6V and adjusts the peak inductor current accordingly.

Thermal Protection

The total power dissipation in LP6492 is limited by a thermal protection circuit. When the device temperature rises to approximately +150 $^{\circ}$ C, this circuit turns off the output, allowing the IC to cool. The thermal protection circuit can protect the device from being damaged by overheating in the event of fault conditions. Continuously running the LP6492 into thermal shutdown degrades device reliability.

Current Limit

The Current limit is set by outside resistance (R_{SEN}), When the CS voltage larger than 53mV/65mV, the current limit is happened that driver can be turned off. The current limit set according to the following equation:

 $I_{OUT} = V_{CS} / R_{SEN}$

Setting Output Voltage

The output voltage is set with a resistor divider from the output node to the FB pin. It is recommended to use divider resistors with 1% tolerance or better. To improve efficiency at very light loads consider using larger value resistors. If the values are too high the regulator is more susceptible to noise and voltage errors from the FB input current are noticeable. For most applications, a resistor in the $10k\Omega$ to $1M\Omega$ range is suggested for R_{UP} and R_{DN} . The output voltage is established by the following equations

$$V_{OUT} = 0.6V \cdot (1 + R_{UP} / R_{DN})$$

Where V_{RFF} is 0.6V.

Output Cable Resistance Compensation

To compensate for resistive voltage drop across the charger's output cable, the LP6492 integrates a simple, user-programmable cable voltage drop compensation using the impedance at the FB pin. The delta V_{OUT} rises when the feedback resistance R_{SEN} value rises, use the equation below:

 $\Delta V_{OUT}(mV)=I_{OUT}(A) \cdot R_{SEN}(m\Omega) \cdot R_{UP}(K\Omega) /40 \text{ K}\Omega$

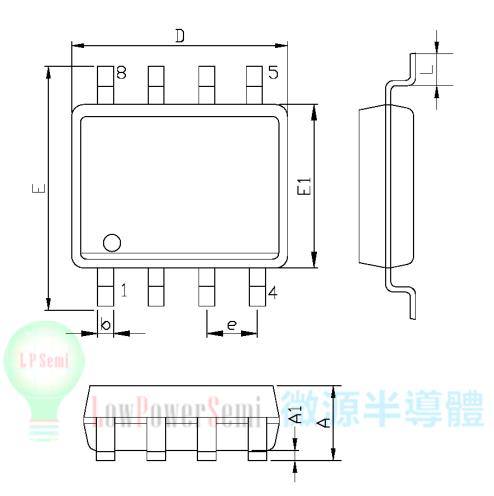
LP6492-02

Jun.-2017

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Packaging Information





SYMBOLS	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	1.35	1.75	0.053	0.069	
A1	0.10	0.25	0.004	0.010	
D	4.90		0.193		
Е	5.80	6.20	0.228	0.244	
E1	3.90		0.1	53	
L	0.40	1.27	0.016	0.050	
ь	0.31	0.51	0.012	0.020	
e	1.27		0.050		

LP6492-02 Jun.-2017 Email: marketing@lowpowersemi.com www.lowpowersemi.com Page 6 of 6